

# On the analogy between the classical wave optics and the quantum wave phenomena

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A striking correspondence between the effects of an auxiliary-mode-assisted transfer of light power between two waveguides and an auxiliary-state-assisted transfer of an electron between two quantum dots is highlighted by the example of an exactly solvable model.

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It has long been known that sometimes the fundamentally different physical phenomena can be described with a common mathematical apparatus. An illustrative example is application of methods of the quantum field theory in condensed matter physics [1]. Another example is some kind of analogy between the classical electromagnetic wave optics and the quantum wave phenomena [2]. Recently, Vorobeichik *et al.* reported the results of experimental study on the light power transfer between two parallel optical waveguides [3]. They have shown that in the presence of periodic longitudinal spatial perturbation of the waveguides, the power transfer is enhanced by about three orders of magnitude. According to their earlier work [4], the power exchange is due to interaction of lowest order waveguide modes with auxiliary high order modes. To analyze the experimental

findings, the authors of Refs. [3, 4] made use of the formal analogy between the Maxwell and Schrödinger equations [2].

In this Letter, by the example of an exactly solvable model, we show that there is not only the mere analogy but a striking one-to-one correspondence between the effect of auxiliary-mode-assisted transfer of light power from the lowest order mode of one waveguide to the lowest order mode of another waveguide and the effect of auxiliary-state-assisted transfer of an electron from the lowest localized state of one quantum dot to the lowest localized state of another quantum dot, the latter being equivalent to the effect of auxiliary-level-assisted coupling of two logical states of the superconducting Josephson-phase qubit suggested to realize a general quantum gate without tunneling [5].

In weakly guiding structures with a slow  $z$ -dependence of the refractive index  $n(\boldsymbol{\rho}, z)$ , the Maxwell equation

$$\Delta E(\boldsymbol{\rho}, z) + k^2(\boldsymbol{\rho}, z)E(\boldsymbol{\rho}, z) = 0 \quad (1)$$

for the nonzero component  $E(\boldsymbol{\rho}, z)$  of a linearly polarized electric field can be rewritten [3, 4] by the substitution

$$E(\boldsymbol{\rho}, z) = \Phi(\boldsymbol{\rho}, z) \exp(ik_0 z) \quad (2)$$

as

$$\left[ -\frac{\hbar_e^2}{2} \nabla_{\boldsymbol{\rho}}^2 + D(\boldsymbol{\rho}, z) \right] \Phi(\boldsymbol{\rho}, z) = i\hbar_e \frac{\partial \Phi(\boldsymbol{\rho}, z)}{\partial z}, \quad (3)$$

where  $\boldsymbol{\rho} = (x, y)$ ,  $k(\boldsymbol{\rho}, z) = 2\pi n(\boldsymbol{\rho}, z)/\lambda$ ,  $k_0 = 2\pi n_0/\lambda$ ,  $n_0$  is the refractive index of the waveguide cladding,  $\lambda$  is the free space wavelength,  $\hbar_e = 1/k_0$ , and

$$D(\boldsymbol{\rho}, z) = \frac{1}{2} \left[ 1 - \left( \frac{n(\boldsymbol{\rho}, z)}{n_0} \right)^2 \right]. \quad (4)$$

The equation (3) for  $\Phi(\boldsymbol{\rho}, z)$  is formally equivalent to the Schrödinger equation

$$\left[ -\frac{\hbar^2}{2m^*} \nabla_{\mathbf{r}}^2 + U(\mathbf{r}, t) \right] \Psi(\mathbf{r}, t) = i\hbar \frac{\partial \Psi(\mathbf{r}, t)}{\partial t} \quad (5)$$

for the wave function  $\Psi(\mathbf{r}, t)$  of an electron moving in the time-dependent potential  $U(\mathbf{r}, t)$ , where  $\mathbf{r} = (x, y, z)$ ,  $m^*$  is the effective electron mass, and  $\hbar$  is the Planck constant. This equation turns into equation (3) for the classical electric field at  $\mathbf{r} \rightarrow \boldsymbol{\rho}$ ,  $t \rightarrow z$ ,  $m^* \rightarrow 1$ ,  $\hbar \rightarrow \hbar_e$ ,  $V(\mathbf{r}, t) \rightarrow D(\boldsymbol{\rho}, z)$ , and  $\Psi(\mathbf{r}, t) \rightarrow \Phi(\boldsymbol{\rho}, z)$ . The eigenenergies  $\varepsilon_n$  of the stationary Schrödinger equation for the eigenfunctions  $\Psi_n(\mathbf{r})$  correspond to the eigenvalues  $d_n$  of the equation for ideal modes  $\Phi_n(\boldsymbol{\rho})$  in the unperturbed waveguide.

The operation of directional couplers is based on beatings between the modal fields of two parallel dielectric waveguides [6], so that the input light power localized in one of the waveguides is transferred completely to another waveguide. Such beatings are the optical analog of the quantum tunneling phenomena. The complete exchange of the light power between the two waveguides takes place at the beating length  $l_b$ . Typically,  $l_b \sim 1$  cm. Increase in the waveguide separation leads to exponential increase in  $l_b$ , so that the directional coupling becomes unobservable. The authors of Refs. [3, 4] succeeded in the orders-of-magnitude reduction of  $l_b$  in such structures through spatial variations of the waveguide geometry. Here we show that this effect is analogous to the fast electron transfer between the quantum dots under the influence of the resonant electromagnetic field [7].

Let us consider a nanostructure composed of two identical semiconductor quantum dots L and R, see Fig. 1. An extra electron occupies initially the lowest size-quantized state  $|L\rangle$  with the energy  $\varepsilon_0$  in the conduction band of the dot L. The lowest state  $|R\rangle$  of the dot R has the same energy and is unoccupied at  $t = 0$ . The wave functions  $\langle \mathbf{r}|L\rangle$  and  $\langle \mathbf{r}|R\rangle$  are

localized in the dots L and R, respectively. If the energy  $\Delta$  of electron tunneling between the two dots is much smaller than the energy separation between the states  $\langle \mathbf{r} | L, R \rangle$  and the nearest excited state of the nanostructure, the electron Hamiltonian can be written as

$$\hat{H}_0 = \varepsilon_0(|L\rangle\langle L| + |R\rangle\langle R|) - \Delta(|L\rangle\langle R| + |R\rangle\langle L|) . \quad (6)$$

The states  $|L\rangle$  and  $|R\rangle$  can be represented as symmetric and antisymmetric superpositions of the eigenstates  $|1\rangle$  and  $|2\rangle$  with the eigenenergies  $\varepsilon_1 = \varepsilon_0 - \Delta$  and  $\varepsilon_2 = \varepsilon_0 + \Delta$ , respectively, as  $|L\rangle = [|1\rangle + |2\rangle]/\sqrt{2}$  and  $|R\rangle = [|1\rangle - |2\rangle]/\sqrt{2}$ . Since the states  $|L\rangle$  and  $|R\rangle$  are not the exact eigenstates of the Hamiltonian  $\hat{H}_0$ , the initial state  $|\Psi(0)\rangle = |L\rangle$  will evolve with time as

$$|\Psi(t)\rangle = e^{-i\hat{H}_0 t/\hbar} |\Psi(0)\rangle = e^{-i(\varepsilon_0 - \Delta)t/\hbar} \left\{ |L\rangle - ie^{-i\Delta t/\hbar} \sin(\Delta t/\hbar) [|L\rangle - |R\rangle] \right\} , \quad (7)$$

so that the electron will tunnel to the dot R in time  $T = \hbar\pi/2\Delta$ . In the case that the energy barrier  $U_b$  separating the dots is high and/or the ratio of the dot spacing  $d$  to the dot size  $a$  is large, the value of  $\Delta$  appears to be exponentially small, so that  $\varepsilon_1 \approx \varepsilon_2 \approx \varepsilon_0$ , and the electron remains localized in the dot L for a macroscopically long time, e. g.,  $T \sim 10^8$  s at  $U_b = 1$  eV and  $d/a = 3$ , see Ref. [7].

In order to facilitate the fast electron transfer between the dots of such a nanostructure, one can make use of the external electromagnetic field [7]. We assume that there is an excited level  $|3\rangle$  in the nanostructure (not necessarily third in order), whose energy  $\varepsilon_3$  is close to the top of the potential barrier separating the dots, so that the corresponding wave function  $\langle \mathbf{r} | 3 \rangle$  is delocalized between the dots. Let the nanostructure be subjected

to a periodic stepwise perturbation

$$V(\mathbf{r}, t) = V(\mathbf{r})f(t) = V(\mathbf{r}) \sum_{j=1}^N \theta(t + \frac{T_0}{2} - jT_0) \theta(jT_0 - t) \quad (8)$$

with the period  $T_0$  and the duration  $T = NT_0 \gg T_0$ . If the value of  $(\varepsilon_3 - \varepsilon_1)/\hbar \approx (\varepsilon_3 - \varepsilon_2)/\hbar$  equals to one of the frequencies  $\Omega_n = 2\pi n/T_0$  in the Fourier expansion

$$f(t) = \sum_k f(\Omega_k) \exp(-i\Omega_k t) , \quad (9)$$

where

$$f(\Omega_k) = \frac{1}{T_0} \int_0^{T_0} dt f(t) \exp(i\Omega_k t) = \frac{\sin\left(\frac{\pi k}{2}\right)}{\pi k} \exp\left(-\frac{i\pi k}{2}\right) , \quad (10)$$

then both states  $|1\rangle$  and  $|2\rangle$  are resonantly coupled to the state  $|3\rangle$ . This coupling results in the coherent evolution of the electron state vector, so that the probability  $p_R$  to find an electron in the state  $|R\rangle$  varies with time as [7]

$$p_R(t) = |\langle R|\Psi(t)\rangle|^2 = \sin^4(\omega t) , \quad (11)$$

where

$$\omega = |\langle R|V(\mathbf{r})|3\rangle| \frac{|f(\Omega_n)|}{\hbar\sqrt{2}} . \quad (12)$$

If  $T = \pi/2\omega + \pi m/\omega$ , where  $m \geq 0$  is an integer, then  $p_R(T) = 1$  and, hence, after the applied perturbation is off at  $t = T$ , the electron will stay localized in the state  $|R\rangle$ . The value of  $T$  can be made many orders of magnitude shorter than in the case of direct electron tunneling between the dots. For example, if the external perturbation is associated with the electric field,  $V(\mathbf{r}) = -e\mathbf{E}_0\mathbf{r}$ , then  $T \sim \hbar/eE_0a \sim 10^{-8}$  s at  $E_0 = 1$  V/cm and  $a = 1$  nm.

Now we turn to the double-waveguide structure. In Ref. [3], the periodic perturbation in the  $z$ -direction was generated by changing the width of the parallel waveguides by

$b = 0.5 \text{ } \mu\text{m}$  in a stepwise fashion, see Fig. 2, so that

$$\Delta n(\boldsymbol{\rho}, z) = (n_0 - n_1)g(\boldsymbol{\rho})f(z) , \quad (13)$$

where  $n_1$  is the refractive index of the waveguide cores,  $g(\boldsymbol{\rho}) = 1$  if  $\boldsymbol{\rho}$  is within the distance  $b$  of the corresponding waveguide side and  $g(\boldsymbol{\rho}) = 0$  otherwise, and

$$f(z) = \sum_{j=1}^N \theta(z + \frac{L_0}{2} - jL_0)\theta(jL_0 - z) . \quad (14)$$

Here the period  $L_0$  and the total length  $L = NL_0$  of the spatial perturbation correspond, respectively, to the period  $T_0$  and the duration  $T$  of the time-dependent perturbation in the case of the resonant electron transfer between the quantum dots. The periodic  $z$ -dependent change in  $D(\boldsymbol{\rho})$  is

$$\Delta D(\boldsymbol{\rho}, z) = -\frac{\Delta n(\boldsymbol{\rho}, z)(n_0 + n_1)}{2n_0^2} = \Delta D(\boldsymbol{\rho})f(z) , \quad (15)$$

where

$$\Delta D(\boldsymbol{\rho}) = \frac{g(\boldsymbol{\rho})}{2} \left[ \left( \frac{n_1}{n_0} \right)^2 - 1 \right] . \quad (16)$$

If the input light power is localized in the left waveguide, then  $\Phi(\boldsymbol{\rho}, z = 0) = \Phi_L(\boldsymbol{\rho})$ , where  $\Phi_L(\boldsymbol{\rho}) = [\Phi_1(\boldsymbol{\rho}) + \Phi_2(\boldsymbol{\rho})]/\sqrt{2}$  is the symmetric superposition of the two lowest order trapped modes,  $\Phi_1(\boldsymbol{\rho})$  and  $\Phi_2(\boldsymbol{\rho})$ , of the unperturbed double-waveguide structure, the corresponding eigenvalues of the Schrödinger-like equation being equal to  $d_1$  and  $d_2$ , respectively ( $d_2 \approx d_1$  for relatively large waveguide separation). Let  $\Phi_3(\boldsymbol{\rho})$  be such a high-order mode with a corresponding eigenvalue  $d_3$  that is spread over the double-waveguide structure and the value of  $(d_3 - d_1)/\hbar_e \approx (d_3 - d_2)/\hbar_e$  equals to one of the wave vectors  $G_n = 2\pi n/L_0$  in the Fourier expansion

$$f(z) = \sum_k f(G_k) \exp(-iG_k z) , \quad (17)$$

where

$$f(G_k) = \frac{1}{L_0} \int_0^{L_0} dz f(z) \exp(iG_k z) = \frac{\sin\left(\frac{\pi k}{2}\right)}{\pi k} \exp\left(-\frac{i\pi k}{2}\right), \quad (18)$$

Making use of the above mentioned correspondence between the equations for  $\Phi(\boldsymbol{\rho}, z)$  and  $\Psi(\mathbf{r}, t)$ , one has for the directional coupling probability of the light power

$$P_R(z) = |\langle R | \Phi(z) \rangle|^2 = \sin^4(Kz), \quad (19)$$

where

$$K = |\langle R | \Delta D(\boldsymbol{\rho}) | 3 \rangle| \frac{|f(G_n)|}{\hbar_e \sqrt{2}}. \quad (20)$$

Here  $|R\rangle$  and  $|3\rangle$  denote the mode  $\Phi_R(\boldsymbol{\rho}) = [\Phi_1(\boldsymbol{\rho}) - \Phi_2(\boldsymbol{\rho})]/\sqrt{2}$  localized in the right waveguide and the delocalized mode  $\Phi_3(\boldsymbol{\rho})$ , respectively. If  $L = \pi/2K + \pi m/K$ , where  $m \geq 0$  is an integer, then  $P_R(L) = 1$  and, hence, the output light power at  $z = L$  will be localized in the right waveguide. It is this effect that has been observed in Ref. [3]. For the waveguide structure studied in Ref. [3] a rough estimate gives  $L = (1 \div 10)$  mm, in a qualitative agreement with the length of the periodic structure 7 mm in Ref. [3]. For the quantitative calculations of the spectrum of the waveguide modes, one should account for all specific details of the structure.

Finally, we note that the most probable reason for incomplete (about 50%) power transfer to the right waveguide and the excitement of different high-order optical modes [3] is the deviation from the "resonant conditions" due to non-optimal waveguide structure parameters. For example, in the case of the laser-induced electron transfer between the quantum dots, when the frequency is offset from resonance [ $\delta = \Omega_n - (\varepsilon_3 - \varepsilon_1)/\hbar \neq 0$ ], the maximum value of  $p_R(t)$  is less than unity, e. g.,  $p_R(T) = 1 - (\pi^2/64)(\delta/\omega)^2$  at  $T = \pi/2\omega$ , see Ref. [7]. The difference in the dot sizes results in  $p_R(T)$  decrease as well [8]. All

expressions derived in Refs. [7, 8] for the ac field perturbed double-dot nanostructure have their analogues in the spatially perturbed double-waveguide dielectric structure and can be used for its engineering.

To conclude, the only essential difference between the two effects considered is that one of them has been observed experimentally [3], while another [5, 7], to the best of our knowledge, not yet. We hope that this Letter will give impetus to experimental research in this direction.

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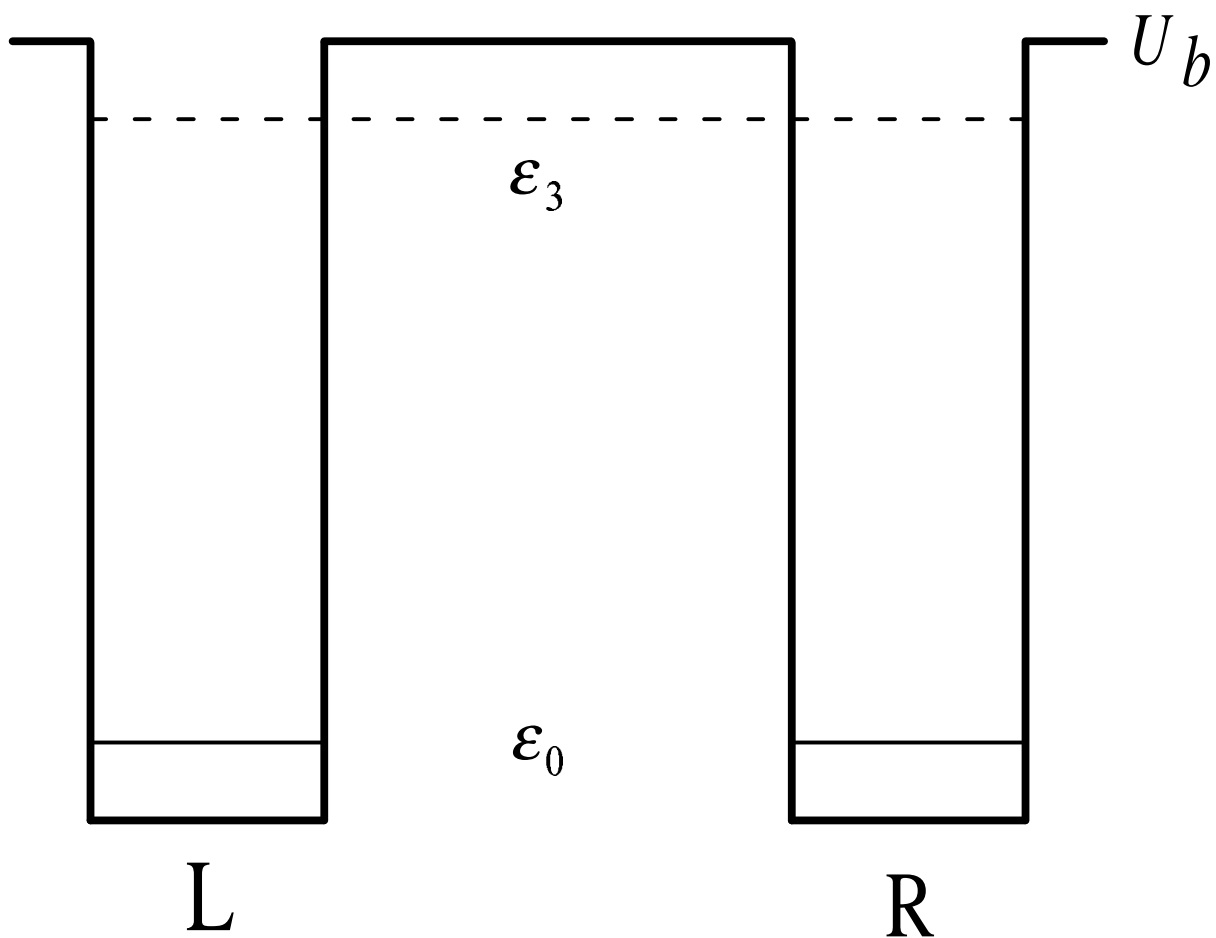


Fig. 1. Schematic energy diagram of the double-dot nanostructure.

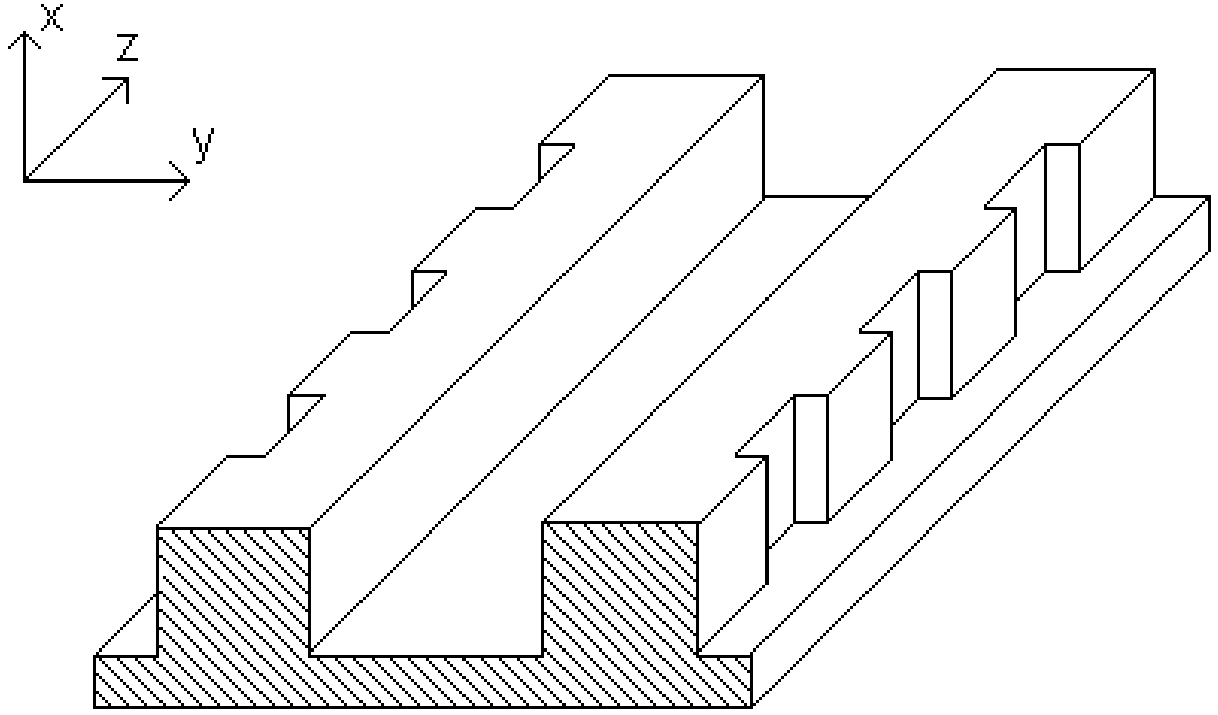


Fig. 2. Schematics of the double-waveguide structure studied in Ref. [3].